

QM10HB2H

Parameter List

Independent BJT Power Module

Part Number	QM10HB2H
Manufacturer	many (see list below)
Status	Historical
Isolated Case (Y/N)	Yes
Circuits Per Package	1
V(BR)CEO (V)	1.0k
V(BR)CBO (V)	600
I(C) Abs.(A) Collector Current	10
Absolute Max. Power Diss. (W)	100
Maximum Operating Temp (°C)	150 [□]
h(FE) Min. Static Current Gain	5.0
@I(C) (A) (Test Condition)	5.0
@VCE (test)	1.0
V(CE)sat Max.(V)	1.0
@I(C) (A) (Test Condition)	5.0
t(r) Max. (s) Rise time	1.5u
t(f) Max. (s) Fall time	9.0u
Package Style	SIP-tab
Pinout Equivalence Code	3-3
Description	Base-Emitter FRD

Notes: □ Junction Temperature

Manufacturers/Sources: _____ Status: _____

Mitsubishi Electric Corp (MITJ)	Historical
Mitsubishi Electronics America Inc (MITS)	Discontinued